Multiple Exciton Generation in Nanostructures for Advanced Photovoltaic Cells

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This paper reviews both experimental and theoretical work on nanostructures showing high quantum yields due to the phenomenon of multiple exciton generation. It outlines the aims and barriers to progress in identifying further such nanostructures and also includes important developments concerning solar devices where nanostructures act as the light-absorbing component. It reports on both semiconductor and carbon structures, both monocomposite (of various dimensionalities) and heterogeneous. Finally, it looks at future directions that can be taken to push solar cell efficiency above the classic limit set by Shockley and Queisser in 1961.

1. Introduction

Current solar energy conversion inefficiency is considered by many to be the greatest barrier to sustainably meet modern day energy needs. Since the early 20th century, there has been an increasing interest in solar voltaics, with early models of p-n junction solar cells manufactured since the 1950s (Figure 1). In 1961, Shockley and Queisser discovered a fundamental limit to the efficiency of a traditional p-n solar cell of 30% [1]. At the end of the 20th century, second-generation solar cells were manufactured which use multiple layers of the semiconducting material. These devices absorb a greater range of frequencies and do surpass this limit, pushing the theoretical limit to a 68% efficiency. However, the manufacture of such multijunction solar cells is too expensive for large-scale commercial use [2]. Theory and experiments show that there is potential to overcome the Shockley–Queisser limit using quantum effects for a new cheap third-generation solar cell [3, 4] (Figure 2). In fact, it is known that impact ionisation in bulk semiconductor materials allows for hot excitons to relax to the valence band, in turn exciting another exciton (Figure 3). However, in bulk, this does not occur at the typical frequencies of solar photons. Therefore, intensive research is being done with the aim of increasing the quantum yield (QY) of photovoltaic cells by enhancing biexciton creation in nanostructures, which allow for a significant response to a wider frequency spectrum. Such structures include nanosheets or “platelets,” nanorods, nanowires, and, notably, quantum dots (QDs). In nanostructures, electron-hole pair multiplication, whereby more than one (typically two) electron-hole pairs are generated by impact with a single incoming photon, is referred to as multiple exciton generation (MEG), to differentiate it from bulk impact ionisation. Let us mention that alternative terminologies, such as “carrier multiplication” (CM) or “multiple exciton collection” (MEC), are also in use in the literature. It is also worth knowing that zero-dimensional structures (quantum dots) may also be referred to as “nanocrystals.”

This review paper is organised as follows: in Section 2, the notion of multiple exciton generation is cursorily recalled, along with some basic related terminologies; Section 3 covers MEG in zero-dimensional (quantum dots) structures, with an emphasis on Pb- and Si-based dots; Section 4 moves onto one-dimensional structures, in particular, to nanorods, nanotubes, and nanoribbons; Section 5 is devoted to two-dimensional structures, such as generic nanosheets and graphene sheets; Section 6 completes our survey focusing on hybrid type II heterostructures, which have drawn interest in
2. Multiple Exciton Generation

The creation of additional carriers from hot excitons has been observed in bulk semiconductors such as PbS, PbSe, and Si [7] and was not included in the seminal analysis by Shockley and Queisser. Theoretical work by De Vos et al. has, however, shown that a QY higher than unity is beneficial for increasing solar device efficiency [8–11]. In a p-n junction solar cell, it has been shown that efficient impact ionisation occurs when the incident photon energy is in excess of five times the energy $E_d$ required to excite an exciton to the valence band, leading to quantum efficiencies above unity [12, 13]. Typically, this is high-energy ultraviolet light outside the solar spectrum. Hence, a key aim in order to exploit this effect is to reduce the threshold energy $h\omega_{th}$ for it to take place so that quantum yields (i.e., the number of excitons per incoming photon) greater than unity can be reached with solar photons. Before 2002, MEG was often referred to as “down-shifting” or “down-conversion” of hot excitons, and devices were theorized, which would facilitate this process [14, 15]. In 2002, however, Nozik was the first to propose that MEG could be enhanced by using nanostructures [16]. Research published soon after by Shaller and Klimov showed evidence for low-threshold MEG in PbSe QDs [17]. Since then, MEG has been observed repeatedly in a variety of QDs such as PbSe [2], PbS [18], and eSi [19], while some semiconductor QDs such as eInAs have, as of yet, shown no signs of MEG [1, 20, 21]. Notably, MEG has also been demonstrated in C structures, such as nanotubes, nanoribbons, and graphene [22].

It is worth noticing that such studies are typically carried out in a colloidal environment, using either photoluminescence, transient absorption, or, more recently,
pump-probe spectroscopy. All of these methods are labour intensive and difficult, and, indeed, the lack of quick and easy QY tests is arguably one of the major barriers in the field [23]. As a consequence, it is only recently that nanostructures have been put into actual devices. The study of such devices is arguably a new field in itself, involving practical and technical considerations that elude the main scope of this review. Although we shall mention several of the most important advances concerning devices, the reader is referred to [24] for a more detailed and exhaustive account.

The early reported QYs of experiments (2005–2010) varied widely up to extremes of 300% [19, 25–27]. It was later discovered that some suspiciously optimistic results were due to photocharging, whereby electrons delocalise from the parent QDs. This gives a deceptive MEG-like signature in the spectroscopic data. Subsequently, it was found that this effect could be nullified simply by stirring the sample solution [28]. Another hurdle in the assessment of QYs for specific structures is clearly the large number of variables involved and relevant to these effects, such as the size, composition, shape, and method of observation. It is uncommon for studies to be done on like-for-like samples so that corroborative results are rare [29]. The complicated interplay between the phonon cooling rate and the nanostructure dimensions is also an important reason for the wide variety in reported QY values [30]. In fact, there is still no general, unified theoretical framework for describing MEG. Nevertheless, all of the studies in the area agree on two key factors: the enhancement of the Coulombic coupling between exciton and biexciton states and the suppression of excitons’ relaxation pathways (predominantly phonon emission) are critical for increasing QY [5, 6, 31, 32]. Such conditions can be achieved by reducing the size of the basic structures, as quantum confinement favours both of them.

As far as the general theory of MEG is concerned, it should be noted that the intriguing possibility of mechanisms hinging on coherent superpositions of multiple excitonic states has been put forward, but it does not agree with all experiments [25, 33]. More recently “window of opportunity” models have been used [34, 35], which allow for more predictive power than previous modelling. They rely on splitting relaxation times into discrete amounts and are often complemented with computer simulations. The main aim of these studies is identifying conditions whereby the threshold photon energy for multiple excitations, $\hbar\omega_{th}$, and the electron-hole pair energy $\epsilon_{th}$ (the energy required for a further exciton to be created) are minimised. In the ideal case scenario, they would approach the limit set by the conservation of energy, when $\hbar\omega_{th} = 2E_g$ and $\epsilon_{th} = E_g$, with $E_g$ being the bandgap energy. This produces a staircase function when plotting pump energy against QY, which is often taken as an optimal reference.

It should be mentioned that when discussing in situ studies, the observed QY is sometimes also termed “quantum efficiency.” When dealing with devices, however, one is typically interested only in their quantum efficiency. This is further qualified as either “external” or “internal” quantum efficiency. The former is the ratio of generated electrons to incident photons, whilst the latter is the ratio of electrons to absorbed photons, which takes into account reflection and transmission, and is always lower. Furthermore, let us remark that, in understanding the relationship between in situ structures and devices, the exciton lifetime $\tau$ plays a key role, as a larger $\tau$ allows for excitons to be “collected,” thus increasing the device’s quantum efficiency.

3. Quantum Dots

Due to their comparative topological simplicity and ease of fabrication, QDs are the best understood class of nanostructures. It is thus not surprising that efforts have been made to design effective ways to assemble devices from QDs and for turning excitons into carriers [36].

In order to be competitive candidates for solar voltaic devices, QDs must have $E_g$ within the infrared region, high QY, and be stable in the cell environment. For these reasons, PbS, PbSe, PbTe, Si, and TiO$_2$ QDs have received the most attention (Figure 4). Computational methods are used in order to identify further possible options [5, 37]. Typically, such methods adopt density-functional theory, which provides a satisfactory compromise between accuracy and scale. In Si$_{20}$H$_{36}$, the MEG dynamics in QDs was probed using density-functional theory [38], placing the threshold for efficient MEG at about $3E_g$, which, for Si$_{20}$H$_{36}$, lies within the visible spectrum. Such computational techniques are bound to furnish additional insight as methods and machines improve. On the other hand, computational methods are typically not designed explicitly to resolve the excited states occupied by biexcitons, which poses challenges and limitations to this approach.

As pointed out above, it is important that photovoltaic structures exhibit quantum confinement. In this regard, theory suggests that, for this to be the case, the radius of the QD should be less than the bulk exciton Bohr radius, calculated as $a_B = \frac{\hbar^2}{\mu}\frac{1}{E_g}$, with $\epsilon$ and $\mu$ being, respectively, the dielectric constant and the reduced mass of the electron and hole. Typical values for such Bohr radii are $a_B$ (PbSe) = 46nm, $a_B$ (PbS) = 20nm, and $a_B$ (Si) = 4.7nm [40]. QDs of these sizes can now by synthesised easily.

3.1. PbX Quantum Dots. Lead-based QDs have been studied intensively, as here $E_g$ is in the low infrared spectrum, fabrication is easily scalable, reproducible, and low cost, and, most importantly, the Bohr exciton radius tends to be large. After initial studies in 2009, it was doubted that PbSe QDs, which, it should be mentioned, feature the added complication of being unstable in air, would exhibit MEG at all [17, 41]. However, in 2010, Beard et al. [12] showed sufficient evidence for MEG, and now, PbSe QDs are possibly the most studied structures in this arena. In 2014, an improvement in PbSe synthesis was introduced that allowed the QDs to survive for up to thirty days in air, showing an increase of orders of magnitude over previous lifetimes [42]. This was made possible by a novel synthetic method whereby PbSe QDs are made directly from CdSe QDs by displacing the Cd with Pb, creating a protective Cl and Cd ion surface on the
made the comparison between PbSe and PbS to determine why QY for PbSe seemed much higher [45]. These two QDs are studied particularly as PbS QDs are stable in air and have the same structure as PbSe QDs which, as already mentioned, are relatively unstable in air. By looking at excited-state lifetimes, it was established that the exciton-biexciton Coulomb coupling was very similar in both QDs. After observing a dependency of QY on the QD size for PbS but not for PbSe, it was also possible to infer that other relaxation channels, specifically the phonon relaxation rate, must be the dominant factor at play in determining the different QYs. This result was instrumental in leading to the first medium-scale collection of QY data on a variety of lead-based QDs of different sizes [44] (Figure 5). In this paper, the accompanying theory is refined with the introduction of the parameters \( \eta \), an MEG efficiency value independent of the pump rate, and \( P \), a factor which describes the competition between the rate of MEG \( (\kappa_M) \) and the rate of nonuseful cooling \( (\kappa_{cool}) \). In PbSe, MEG occurs at about \( 2.0 \times E_g \), which is described by a \( \eta \) value between 0.4 and 0.5 (Figure 6). The following empirical equation relates \( P \) with the photon energies involved:

\[
\kappa_M = P \left( \frac{h \nu_{ph}}{h \nu_{th}} \right)^s,
\]

where \( s \) is a factor which describes how MEG changes with \( h \nu_{ph} \) and the excess pump photon energy \( h \nu_{ex} \). Here, \( s \) is found to be around 2.2 for lead-based QDs. The study by Midge et al. [28] and Mihaylov et al. [38] in agreement with previous relevant literature also reports on properties for a variety of PbS,Se\(_{1-x}\) alloy QDs, with varying composition and radius, allowing one to draw conclusions about the size dependence of \( \eta \) for the different compositions of QDs (Figure 6). It is suggested that higher MEG might be achievable in nonspherical crystal structures, although more data need to be collected to explore such configurations.

3.2. Si Quantum Dots. Silicon is abundant in nature. It makes up over 90% of solar voltaic devices currently in use and plays a huge role in electronics and technology. It poses no environmental issues, and Si membranes are optically transparent to nonbandgap energy photons, such that it would be possible to create Si multilayer cells of different sizes in order to span a wider absorption spectrum and achieve greater efficiency [46]. It also has \( QD \cdot E_g \) within the infrared, making it potentially an ideal material for third-generation solar cells.
QY above unity with silicon QDs was first reported in 2007 by Beard et al. [19] who tested QDs of two different diameters: one in the strong confinement region (below the Bohr exciton radius for Si of 4.9 nm) and the other in the weak-intermediate confinement region (about double the Bohr exciton radius). MEG was thus observed in a colloidal environment for both of these QDs at a pump energy of 0.86 eV. The reconstructed value for the electron-hole energy was $\varepsilon_{eh} = (2.4 \pm 0.1)\,E_g$ (close to the energy conservation limit of $2E_g$), with a reported QY of 2.3 ± 0.2 at $3.4E_g$. Other relaxation pathways other than phonon emission were also taken into account in this study, such as charge transfer and radiative recombination [3].

In 2016, Bergren et al. used pump-probe spectroscopy to study a range of differently sized Si QDs [47]. As will be discussed below, in recent years, emphasis has been on trying to extend biexciton lifetimes, which is the angle taken by Bergren et al. in this work. Thus, they found that, as one should expect, biexciton lifetimes increase as the diameter is reduced, and postulate that the increase in the quantum confinement is reducing the coupling to the phonon relaxation channels. This is consistent with evidence for other QDs.

Study of Si QD films is also intensive due to easy access to high-grade samples. In [48], a novel way to induce MEG in an array of Si QDs was described, showing that if the QDs are in close proximity, hot excitons can excite excitons in neighbouring QDs rather than in their parent QDs. Specifically, this experiment used Si QDs of around 1.8 nm embedded in a SiO₂ matrix. MEG obtained through such a thermal exciton propagation enjoys a reduced chance of Auger recombination, and exciton lifetime prolonged by up to six orders of magnitude. A recent paper by Kryjevski and Kilin [49] adopts density-functional theory to evaluate the effect of changing the internal structure of the QDs in amorphous QDs, as opposed to crystalline ones: such computer simulations predict a considerable change in dynamics in the two-dimensional density limit present in films. They suggest that, in this case, amorphous QDs may show a marked improvement in QY, along with better carrier mobility.

Recently, research has increasingly focused on novel structures rather than on mere manipulation of the QD size. The production and characterisation of all multilayer Si cells with different bandgaps due to different levels of P dopant, rather than due to different sizes, have been first explored [46]. High levels of MEG in GeX QDs and higher QYs than in bulk GeX were subsequently observed in these structures [50], with external quantum efficiency exceeding 120% for PbTe QDs [51]. It is perhaps worth noting that such studies, which focus on external QYs, are key to showing that the in situ study feature behaviours can be replicated for real-world usage.

### 4. One-Dimensional Structures

Over the last few years, one-dimensional structures have started to draw attention as candidates for photovoltaic devices alternative to quantum dots. Whilst clearly more challenging to synthesise than zero-dimensional dots, higher-dimensional structures entail a breaking of the spherical symmetry that lifts some of the energy level degeneracies and thus allows for additional excitations. Besides, theoretical models suggested that, despite the increased volume of one-dimensional structures such as nanorods, they would still lie in the quantum confinement region, as the effect of quantum
confinement depends not merely on the total volume of a structure but rather on its effective cross-sectional area [52, 53]. In terms of MEG, nanowires have only been considered in preliminary computational studies [38, 49]. On the other hand, cell architectures based on nanorods and nanotubes have received some attention [54].

4.1. Nanorods. Pb-based nanorods were the first nonspherical structures to be studied for MEG, which was made possible by synthetic methods developed in 2010 [55, 56]. Initial reports showed the first evidence of MEG [57, 58]. In particular, in a paper by Cunningham et al. [58], values of $\hbar \omega_{th}$ and $\epsilon_{th}$, close to the ideal values of $2E_g$ and $E_g$, were reported. The key issue in these studies is clearly to achieve a general understanding of the effect of length and aspect ratio on QYs. The PbSe nanorods' QY dependence on the aspect ratio (defined as $\rho = \text{length/diameter}$) was investigated soon afterwards [39, 59], indicating that higher efficiency may be due to increased exciton Coulombic couplings at certain $\rho$, as suggested in [52]. After testing samples with different $\rho$ and $E_g$, it was found that the QY has a nonlinear, nonmonotonic dependence with $\rho$, displaying an almost threefold increase at certain $\rho$ values (Figure 7); in particular, the efficiency peaks at $E_g$ values exceeding unity for PbSe nanorods [60]. More specifically, external QYs of $109 \pm 3\%$, $113 \pm 3\%$, and $122 \pm 3\%$ were measured for devices containing nanorods of $E_g = 1.05$eV, $E_g = 0.95$eV, and $E_g = 0.80$eV. This is a promising result, which gives confidence that the same structures could be used in future devices. In the same study, the internal QY was shown to be in very good agreement with preexisting experimental and theoretical literature [59, 61].

4.2. Carbon Nanotubes and Nanoribbons. Theoretical work from 2004 suggested that strong Coulombic interactions between carriers would be present in single-walled carbon nanotubes (SWCNTs) [63, 64]. This and other characteristics such as interesting photo and electric properties, as well as strong photon absorption, imply that such structures have the potential for MEG. Despite being considered a 1D material, the dynamics that governs MEG in SWCNTs is different to nanorods or nanowires. This is because excitons are confined to the surface of the SWCNTs rather than at their centre, which implies a quasi-2D behaviour.

An initial 2008 study tested a SWCNT sample with mixed chiralities [65] showing a QY of 130% for $\hbar \omega = 3.7 E_g$. A paper published two years later performed the same experiment with SWCNTs of specific chiralities [66]. The latter, by Wang et al., achieved the same QY at $\hbar \omega = 3E_g$ for [7, 8] SWCNTs. However, both these results show values of $\hbar \omega_{th}$ outside the solar spectrum. Biexciton creation was further reported in 2013 [67], although no QY is quoted there. A basic hurdle toward the exploitation of SWCNTs in photovoltaic cells is represented by the difficulty of synthesing samples of a single chirality, which require labour-intensive retroprocesses. For more information about the uses of SWCNTs in the solar voltaic system outside of enhancing MEG, see [68, 69].

Recently, MEG has been investigated in graphene nanoribbons (GNRs) using transient absorption [70]. GNRs have the advantage of having synthesis methods of atomic precision [71]. Furthermore, MEG turns out to be enhanced in these structures compared to SWCNTs, as they can be made extremely narrow with a significantly smaller surface area per unit length. The study of GNRs may still be considered to be in its infancy. However, initial theoretical reports indicate potential for extraordinary photoelectric properties [72–74].

![Figure 7](image-url)
5. Nanosheets

Synthetic methods for semiconductor nanosheets are still imprecise and difficult, and as such, they are the greatest barrier to their study [75]. In 2014, Aerts et al. [76] used a method of synthesis described in [77] to make ultrathin PbS nanosheets and test them via transient absorption (Figure 8). Sheets of three thickness, 4.0 ± 0.1, 5.9 ± 0.1, and 7.0 ± 0.1 nm, gave values for the maximum transient absorption bleaching ΔTmax/T, where T is temperature, which could be inserted into the equation

\[ \frac{\Delta T_{\text{max}}}{T} = \Omega \sigma_{TB} I_0 F_A \]  

(2)

to determine the QY, Ω. The transient bleach cross section σTB was determined from low-energy pumping with a known incident number I0F_A of photons per unit area. The data analysis shows the notable result that hωth = 3eV is not affected by the nanosheet’s thickness or E_g. Most remarkably, it also shows that, for the thinnest nanosheet of 4 nm, one has η = 0.9 ± 0.15. This is extremely close to the optimal value of η = 1 and would suggest that all excess energy has gone into exciting multiple carriers. Note that this is significantly larger than the reported values for PbX QDs, which is around η = 0.3–0.5 [41, 44, 59]. Unfortunately, these nanosheets have the disadvantage of high hωth, although the ability to exhibit near-perfect efficiency once the threshold frequencies are reached is extremely interesting per se.

5.1. Graphene. A more readily available 2D structure with well-established synthesis is graphene, whose promise for useful optoelectric properties, such as high carrier densities
and charge mobility, is well known [78]. Between 2010 and 2012, theoretical work by Winzer et al. showed that graphene has the potential for MEG [79, 80]. Only a year later, Tielrooij et al. [81] carried out a study on MEG biexciton creation in graphene through methods similar to those that would then be used in [76] on PbSe nanosheets. Such a study identifies two dominant processes: carrier-carrier scattering, leading to MEG, and phonon-assisted cooling, as well as a branching ratio between the two, which is shown to be highly favourable for MEG. This study employed doped graphene and suggests a dependence of the results on the doping levels, which would open the additional possibility to alter the threshold energies for MEG by changing the amount of dopant as with Si. Soon after, in 2014, MEG was detected in low-doped graphene too [82].

It should be mentioned that graphene has been studied in a wide variety of roles inside devices, not only as the light-absorbing component. To find out more about its role in enhancing photo-induced voltage in dye-sensitised solar cells and QD cells, see the review paper [83].

6. Type II Heterostructures

New QD structures that aim to separate the hole and electron wave functions have emerged recently. The wave function separation suppresses Auger recombination and thus increases the exciton lifetime [34]. These “type II” heterostructures are created by using multiple different compositions in the same structure (Figure 9).

A prominent example of a heterostructure is represented by core-shell QDs, such as those studied in the work of Cirloganu et al. in [84], on the basis of a phenomenological model for MEG proposed by Stewart et al. [35], which suggests that slowing down hot carrier relaxation might be even more important than previously thought. In general, this work has spurred an interest in cooling-rate engineering for nanostructures, and in turn, much research into how the separation between electron and hole wave functions may be increased.

Cirloganu et al. propose that the electron wave functions are spread over the whole structure, while the hole wave functions are localised around the core, creating the desired spatial separation, and proceed to study QDs with a PbSe core and a CdSe shell of varying sizes; such dots can be characterised by an aspect ratio \( \rho \), defined as the ratio of shell thickness to the overall radius. Thus, consistently higher MEG rates than reported for PbSe QDs were observed for core-shell QDs. A critical aspect ratio, which would provide the energy-conservation limit of \( \eta = 1 \), is predicted to lie in the interval \( \rho_c = 0.45–0.7 \). Further related analysis on the effect of core-shell aspect ratio, as well as of the degree of alloying between the core and the shell and its spectrographic implications, can be found in the review [85].

In the same year, Eshet et al. looked at heterostructured nanorods of CdSe and CdS [86] created by a seeded-growth approach [87]. They analysed both seeded and core-shell structures, obtaining results which comply with the standard behaviour above \( h\omega_{th} \); for the seeded structures, the efficiency \( \eta \) increases with the seed size, while for the core/shell structures, \( \eta \) increases as the core diameter decreases. However, when probing the samples in the non-MEG regime (\( h\omega < h\omega_{th} \)), it was found that, unexpectedly, \( \eta \) actually decreases with decreasing core size, which is converse to theoretical prediction as well as monocomposite QD behaviour. A 2016 paper by Eshet et al. furthered the inquiry into how \( h\omega_{th} \) could be lowered from previous values of around \( 3E_g \) by analysing the dynamics of nanorod heterostructures whose composition changes from one to the other end of the rod. The theory suggests that, in this class of heterostructures, the internal electric field generated from photon pumping would aid MEG. When pumping around the energy conservation limit of \( h\omega = 2E_g \), MEG efficiencies of 10%–20% were observed.

No semiconductor heterostructures were investigated in 2D-confined systems. However, there has been research into the so-called “Van der Waals” graphene heterostructures [88] (Figure 10). These consist of layers of graphene separated by nanosheets of other materials, such as MoS\(_2\) or WSe\(_2\). MEG studies on this kind of “material stacks” proved inconclusive [89], and further research is needed to shed light as to their potential.
7. Summary and Outlook

The technology required to create new generations of cheap and efficient solar cells is still a way off its ultimate goal. Despite this, since 2002, there have been significant breakthroughs in the study of nanostructures to overcome the Shockley–Queisser limit. Through generating multiple pairs of excitons per incident photon, efficiencies have been measured strongly, indicating that this goal should be achievable. As this compact review strived to show, experimental progress has led to a better understanding of the dynamics which governs excitons experiencing zero-, one-, and two-dimensional quantum confinement. Work by computational and theoretical groups has led to research which allows for better prediction in future candidates for MEG and better prediction of the effect various factors such as aspect ratio or size might have.

Quantum dots in a colloidal environment have now moved onto being studied in device environments. To some extent, monocomposite QDs are being put to one side in favour of studies into heterostructures. The most state-of-the-art and applicable results have come from the creation of actual devices and measurement of high external quantum efficiencies [42, 51, 60]. Whilst they have yet to show voltages exceeding the Shockley–Queisser limit, such devices have given external QYs showing that MEG does work when turning excitons into carriers. To these aims, the potential of carbon structures is still not well understood in the one- and two-dimensional regimes. However, research has conclusively shown that higher-dimensional architectures do reach extremely high efficiencies at threshold frequencies outside the solar spectrum [82, 90]. Attempts to reduce the threshold energy by using ribbons, multilayers of graphene, and other systems are underway.

Future investigation into the possibility of creating nanorod and nanosheet devices seems to be in order, as well as into the effect of the nanostructure environment on the MEG efficiency. In particular, a better understanding of the latter seems to be a key to really appreciate the impact these combined advances might have toward potentially revolutionary results. It should also be noted that MEG itself is unlikely to be the only pathway toward third-generation solar cells. It is one of the many phenomena being explored that could come together in order to create such devices. It seems fair to predict that when this research is combined with other work into the effect of electric fields on solar voltaic performance, or tandem cells, the application of nanostructures to light harvesting might achieve enhanced efficiencies in both proof-of-principle experiments and operational devices in the short or medium term.

Conflicts of Interest

The authors declare that there are no conflicts of interest regarding the publication of this paper.

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